Plastic Power Transistors

NPN Silicon DPAK For Surface Mount Applications

Designed for high-gain audio amplifier applications.

Features

- High DC Current Gain
 - $h_{FE} = 120 \text{ (Min)} @ I_C = 500 \text{ mA}$ = 40 (Min) @ I_C = 2 A
- Low Collector-Emitter Saturation Voltage V_{CE(sat)} = 0.3 Vdc (Max) @ I_C = 1 A
- High Current–Gain Bandwidth Product $f_T = 65 \text{ MHz} (\text{Min}) @ I_C = 100 \text{ mA}$
- Epoxy Meets UL 94 V-0 @ 0.125 in
- ESD Ratings: Human Body Model, 3B > 8000 V Machine Model, C > 400 V
- These are Pb-Free Packages

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Base Voltage	V _{CB}	50	Vdc
Collector-Emitter Voltage	V _{CEO}	50	Vdc
Emitter-Base Voltage	V_{EB}	5	Vdc
Collector Current Continuous Peak	Ι _C	2 3	Adc
Base Current	Ι _Β	0.4	Adc
Total Device Dissipation @ T _C = 25°C Derate above 25°C	PD	15 0.1	W W/°C
Total Device Dissipation @ T _A = 25°C* Derate above 25°C	P _D	1.68 0.011	W W/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +175	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance Junction-to-Case Junction-to-Ambient*	$R_{ extsf{ heta}JC} \ R_{ heta}JA$	10 89.3	°C/W

*These ratings are applicable when surface mounted on the minimum pad sizes recommended.

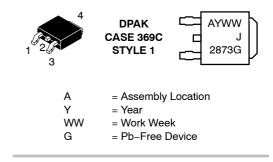


ON Semiconductor®

http://onsemi.com

SILICON POWER TRANSISTORS 2 AMPERES 50 VOLTS 15 WATTS

> MARKING DIAGRAM



ORDERING INFORMATION

Device	Package	Shipping [†]
NJD2873T4G	DPAK (Pb–Free)	2500 Units / Reel

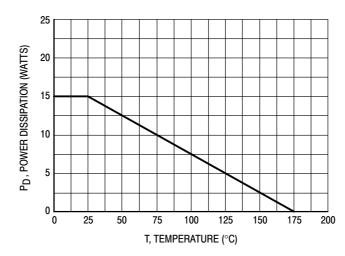
+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS (T_C = 25° C unless otherwise noted)

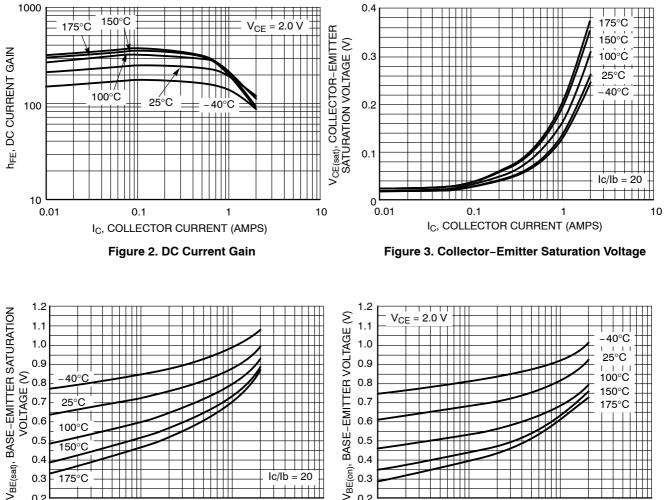
Characteristic	Symbol	Min	Max	Unit	
OFF CHARACTERISTICS					
Collector–Emitter Sustaining Voltage (Note 1) $(I_C = 10 \text{ mAdc}, I_B = 0)$	V _{CEO(sus)}	50	_	Vdc	
Collector Cutoff Current (V _{CB} = 50 Vdc, I _E = 0)	I _{CBO}	_	100	nAdc	
Emitter Cutoff Current ($V_{BE} = 5 \text{ Vdc}, I_C = 0$)	I _{EBO}	_	100	nAdc	
ON CHARACTERISTICS					
DC Current Gain (Note 1) (I _C = 0.5 A, V _{CE} = 2 V) (I _C = 2 Adc, V _{CE} = 2 Vdc) (I _C = 0.75 Adc, V _{CE} = 1.6 Vdc, $-40^{\circ}C \le T_J \le 150^{\circ}C$)	h _{FE}	120 40 80	360 - 360	-	
Collector–Emitter Saturation Voltage (Note 1) $(I_{C} = 1 \text{ A}, I_{B} = 0.05 \text{ A})$	V _{CE(sat)}	-	0.3	Vdc	
Base-Emitter Saturation Voltage (Note 1) ($I_C = 1 \text{ A}$, $I_B = 0.05 \text{ Adc}$)	V _{BE(sat)}	_	1.2	Vdc	
$ \begin{array}{l} \text{Base-Emitter On Voltage (Note 1)} \\ (I_C = 1 \; \text{Adc}, \; V_{CE} = 2 \; \text{Vdc}) \\ (I_C = 0.75 \; \text{Adc}, \; V_{CE} = 1.6 \; \text{Vdc}, \; -40^\circ \text{C} \leq T_J \leq 150^\circ \text{C}) \end{array} $	V _{BE(on)}		1.2 0.95	Vdc	
DYNAMIC CHARACTERISTICS					
Current–Gain – Bandwidth Product (Note 2) (I _C = 100 mAdc, V _{CE} = 10 Vdc, f _{test} = 10 MHz)	f _T	65	-	MHz	
Output Capacitance (V_{CB} = 10 Vdc, I _E = 0, f = 0.1 MHz)	C _{ob}	-	80	pF	

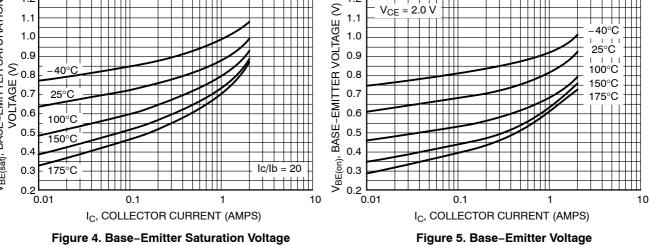
1. Pulse Test: Pulse Width = 300 μ s, Duty Cycle \approx 2%. 2. $f_T = |h_{fe}| \bullet f_{test}$.

TYPICAL CHARACTERISTICS









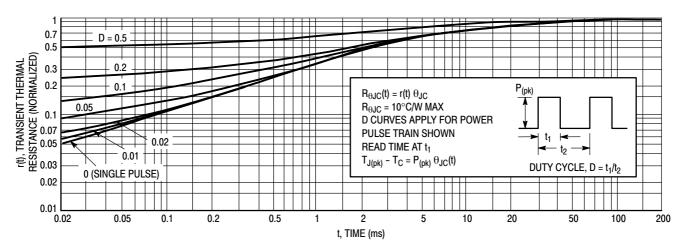
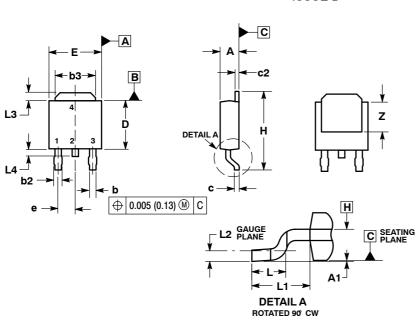


Figure 6. Thermal Response

PACKAGE DIMENSIONS



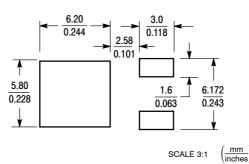
DPAK CASE 369C-01 ISSUE D

NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- 2. CONTROLLING DIMENSION: INCHES. 3. THERMAL PAD CONTOUR OPTIONAL WITHIN DI-
- THEHMAL PAD CONTOUR OPTIONAL WITHIN DI-MENSIONS b3, L3 and Z.
 DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.006 INCHES PER SIDE.
 DIMENSIONS D AND E ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY.
 DATUMS A AND B ARE DETERMINED AT DATUM DI AND E H
- PLANE H.

	INCHES		MILLIMETER		
DIM	MIN	MAX	MIN	MAX	
Α	0.086	0.094	2.18	2.38	
A1	0.000	0.005	0.00	0.13	
b	0.025	0.035	0.63	0.89	
b2	0.030	0.045	0.76	1.14	
b3	0.180	0.215	4.57	5.46	
С	0.018	0.024	0.46	0.61	
c2	0.018	0.024	0.46	0.61	
D	0.235	0.245	5.97	6.22	
Е	0.250	0.265	6.35	6.73	
е	0.090 BSC		2.29 BSC		
Н	0.370	0.410	9.40	10.41	
L	0.055	0.070	1.40	1.78	
L1	0.108 REF		2.74 REF		
L2	0.020 BSC		0.51 BSC		
L3	0.035	0.050	0.89	1.27	
L4		0.040		1.01	
Z	0.155		3.93		

SOLDERING FOOTPRINT*



STYLE 1: PIN 1. BASE

2. COLLECTOR 3. EMITTER

COLLECTOR 4.

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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